

NCE07TD60BD

600V, 7A, Trench FS II Fast IGBT

General Description:

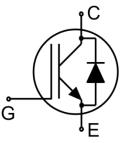
Using NCE's proprietary trench design and advanced FS (Field Stop) second generation technology, the 600V Trench FSII IGBT offers superior conduction and switching performances, and easy parallel operation;

Features

- Trench FSII Technology Offering
- Very low V_{CE(sat)}
- High speed switching
- Positive temperature coefficient in V_{CE(sat)}
- Very tight parameter distribution
- High ruggedness, temperature stable behavior

Application

- Air Condition
- Inverters
- Motor drives



Schematic diagram

Package Marking and Ordering Information

| Device | Device Package | Device Marking |
|-------------|----------------|----------------|
| NCE07TD60BD | TO-263 | NCE07TD60BD |



TO-263

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

| Symbol | Parameter | Value | Units |
|----------------------------------|--|-------------|-------|
| V _{CES} | Collector-Emitter Voltage | 600 | V |
| V_{GES} | Gate- Emitter Voltage | ±30 | V |
| | Collector Current | 14 | Α |
| lc | Collector Current @T _C = 100 °C | 7 | А |
| I _{Cplus} | Pulsed Collector Current, tp limited by T _{jmax} | 21 | А |
| - | turn off safe operating area, V _{CE} =600V, T _J =150°C | 21 | А |
| l _F | Diode Continuous Forward Current @T _C = 100 °C | 7 | А |
| Іғм | Diode Maximum Forward Current | 21 | А |
| Б | Power Dissipation @ T _C = 25°C | 73 | W |
| P _D | Power Dissipation @Tc = 100 °C | 36.5 | W |
| T _J ,T _{stg} | Operating Junction and Storage Temperature Range | -55 to +175 | °C |
| TL | Maximum Temperature for Soldering | 260 | °C |
| tsc | Short circuit withstand time V _{GE} =15V, V _{CC} ≤400V, Allowed number of short circuits<1000Time between short circuits:≥1.0s,T _j ≤150°C | 5 | us |

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Thermal Characteristic

| Symbol | Parameter | Value | Units |
|--------|--|-------|-------|
| Rejc | Thermal Resistance, Junction to case for IGBT | 2.05 | °C/W |
| Rejc | Thermal Resistance, Junction to case for Diode | 2.50 | °C/W |
| Reja | Thermal Resistance, Junction to Ambient | 62 | °C/W |

Electrical Characteristics (Tc=25°C unless otherwise noted)

| 0 | Description | T | Value | 11 | | | | |
|----------------------|--|--|-----------------------|------|------|------|-------|--|
| Symbol | Parameter | Test Conditions | | Min. | Тур. | Max. | Units | |
| Static Chara | cteristics | | | | | | | |
| V _{(BR)CES} | Collector-Emitter Breakdown Voltage | V _{GE} =0V | ,I _{CE} =1mA | 600 | | | V | |
| Ices | Collector-Emitter Leakage Current | V _{GE} =0V, | Vce=600V | | | 4 | uA | |
| I _{GES(F)} | Gate to Emitter Forward Leakage | V _{GE} =+30 | V,Vce=0V | | | 100 | nA | |
| I _{GES(R)} | Gate to Source Reverse Leakage | V _{GE} =-30 | V,Vce =0V | | | 100 | nA | |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | Ic=5A | Tj=25°C | | 1.7 | 1.9 | V | |
| V CE(sat) | Collector-Emitter Saturation voltage | $V_{GE}=15V$ | Tj=100°C | | 1.9 | | V | |
| $V_{\text{GE(th)}}$ | Gate Threshold Voltage | Ic=1mA | ,Vce=Vge | 4.0 | 5.0 | 6.0 | V | |
| Dynamic Ch | aracteristics | | | | | | | |
| Cies | Input Capacitance | \/ 05\ | | | 675 | | | |
| Coes | Output Capacitance | V _{CE} =25V, V _{GE} =0V, f=1MHz | | | 22 | | pF | |
| Cres | Reverse Transfer Capacitance | | | | 13 | | | |
| Qg | Total Gate Charge | | | | 28 | | | |
| Q _{ge} | Gate to Emitter Charge | V _{CC} =480V, I _C =7A, V _{GE} =15V | | | 8 | | nC | |
| Q _{gc} | Gate to Collector Charge | | | | 13 | | | |
| I _{C(SC)} | Short circuit collector current Max.1000 short circuits Time between short circuits: ≥1.0s | V _{GE} =15V,V _{CC} ≤400V, t _{SC} ≤5us,Tj≤150°C | | | 34 | | А | |
| Switching Cl | haracteristics | | | | | | | |
| $t_{d(ON)}$ | Turn-on Delay Time | | | | 20 | | | |
| t _r | Rise Time | | | | 15 | | 20 | |
| t _{d(OFF)} | Turn-Off Delay Time | V_{CC} =400V, I_{C} =7A, V_{GE} =0/15V, R_{g} =5 Ω | | | 73 | | ns | |
| t _f | Fall Time | | | | 18 | | | |
| Eon | Turn-On Switching Loss | Inducti | ve Load | | 0.21 | | | |
| E _{off} | Turn-Off Switching Loss | | | | 0.10 | | mJ | |
| Ets | Total Switching Loss | | | | 0.31 | | | |

Electrical Characteristics of the Diode(Tc= 25°C unless otherwise specified):

| Cumbal | Parameter | Test Conditions | Rating | | Units | |
|-----------------------------|-------------------------------------|-----------------------------------|--------|------|-------|-------|
| Symbol | Parameter | rest Conditions | Min. | Тур. | Max. | Units |
| V_{FM} | Diode Forward Voltage | I _F =7A | | 1.5 | 1.7 | V |
| Trr | Reverse Recovery Time | | | 230 | | ns |
| I _{RRM} | Diode Peak Reverse Recovery Current | I _F =7A, di/dt=200A/us | | 3.5 | | А |
| Qrr | Reverse Recovery Charge | | | 0.44 | | uC |
| Pulse width t _{tp} | ≤380μs,δ≤2% | | | | | |

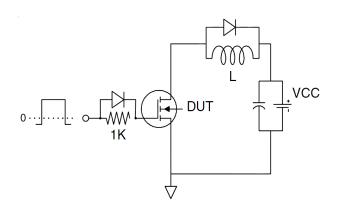
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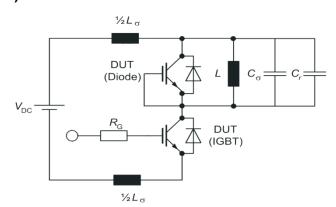
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Test Circuit

1) Gate Charge Test Circuit

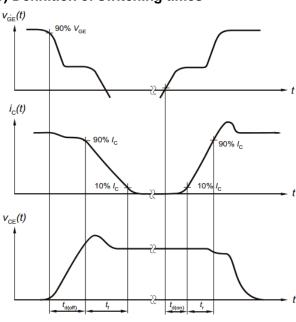


2) Switch Time Test Circuit

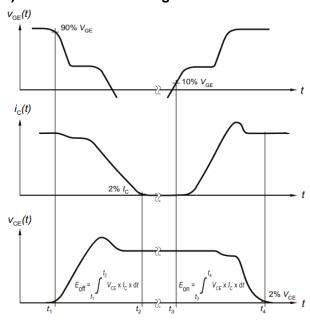


Switching characteristics

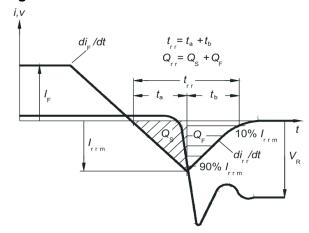
1) Definition of switching times



2) Definition of switching losses



3) Definition of diode switching characteristics







Typical Electrical and Thermal Characteristics

Figure 1 Output Characteristics

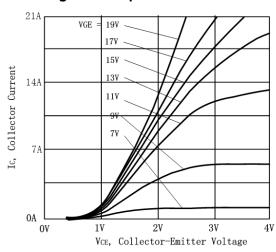


Figure 3 V_{CEsat} vs. Case Temperature

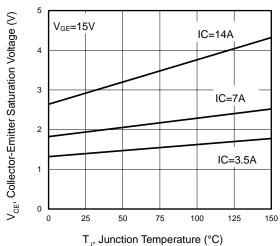


Figure 5 Capacitance Characteristics

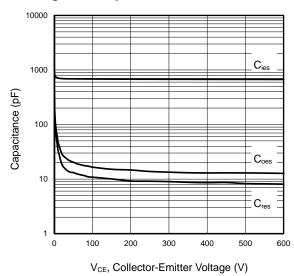


Figure 2 Transfer Characteristics

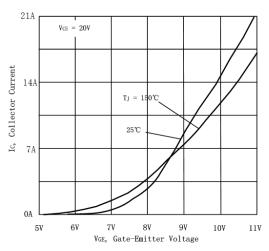


Figure 4 Saturation Voltage vs. V_{GE}

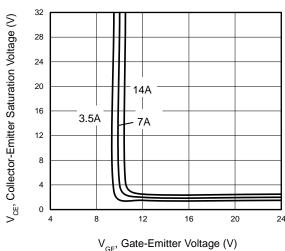
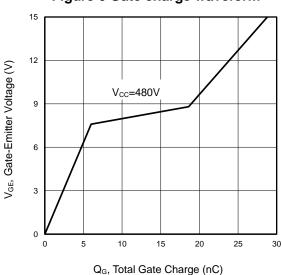


Figure 6 Gate charge waveform



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Typical Electrical and Thermal Characteristics

Figure 7 Forward Characteristics

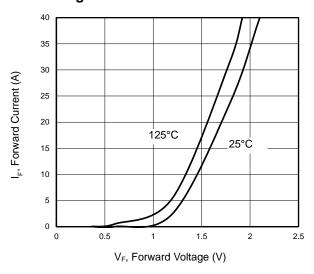


Figure 9 Typical Switching Times as a Function of Gate Resistor

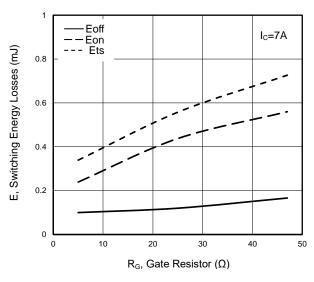


Figure 11 Gate-emitter Threshold Voltage as a Function of Junction Temperature

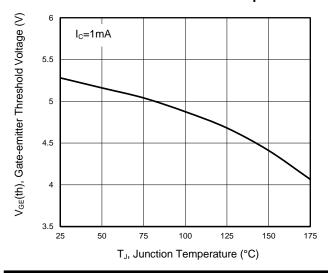


Figure 8 V_F vs. Temperature

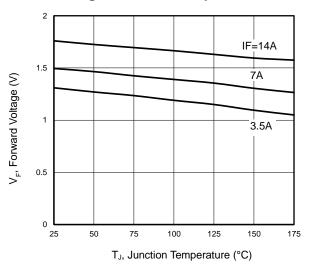


Figure 10 Typical Switching Times as a Function of Junction Temperature

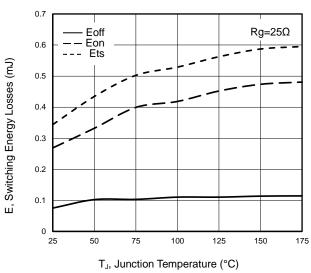
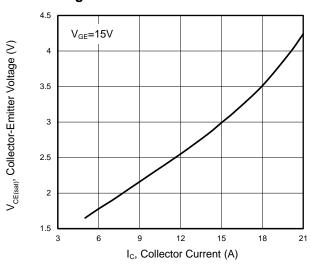


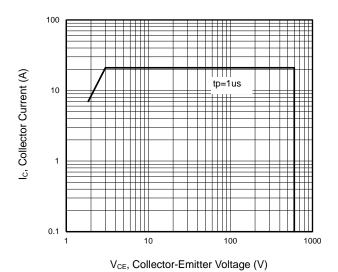
Figure 12 Typical Collector-emitter Saturation
Voltage as a function of Collector Current



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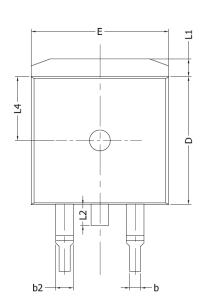
Typical Electrical and Thermal Characteristics

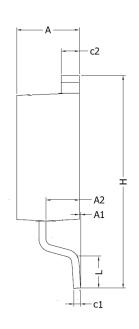
Figure 13 Forward Bias Safe Operating Area

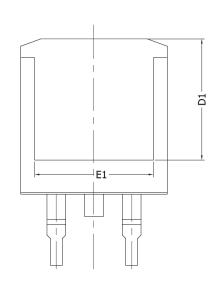




TO-263-3L Package Information







| Symbol | Dimensions In Millimeters | | Dimensions In Inches | | |
|--------|---------------------------|-------|----------------------|------|--|
| Cymbol | Min. | Max. | Min. | Max. | |
| Α | 4.40 | 4.60 | 0.17 | 0.18 | |
| A1 | 0.00 | 0.25 | 0.00 | 0.01 | |
| A2 | 2.20 | 2.60 | 0.09 | 0.10 | |
| b | 0.76 | 0.89 | 0.03 | 0.04 | |
| b2 | 1.23 | 1.37 | 0.05 | 0.05 | |
| С | 0.47 | 0.60 | 0.02 | 0.02 | |
| c1 | 0.46 | 0.56 | 0.02 | 0.02 | |
| c2 | 1.25 | 1.35 | 0.05 | 0.05 | |
| D | 0.91 | 0.93 | 0.04 | 0.04 | |
| D1 | 8.00 | - | 0.31 | - | |
| E | 9.80 | 10.00 | 0.39 | 0.39 | |
| E1 | 7.80 | - | 0.31 | - | |
| е | 2.54 | IBSC | 0.10 | BSC | |
| Н | 14.90 | 15.70 | 0.59 | 0.62 | |
| L | 2.00 | 2.60 | 0.08 | 0.10 | |
| L1 | 1.17 | 1.40 | 0.05 | 0.06 | |
| L2 | - | 1.75 | - | 0.07 | |
| L4 | 4.60REF | | 0.18 | REF | |

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